Analog Power

N-Channel 60-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	$I_D(A)$		
60	$89@V_{CS} = 10V$	±4.0		
00	$104@V_{CS}=4.5V$	±3.7		
	DIC-8 View 8 \Box D1 $G_1 \sim \Box$	B_1 B_2		
2	7 🗖 D1			
3	6 🗖 D2	\dot{S}_1 \dot{S}_2		
4	5 D2 N-Cha MOS	annei N-Chan		

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage		VDS	60	V		
Cate-Source Voltage		V _{c8}	±20			
	$T_A=25^{\circ}C$	т_	±4.0			
Continuous Drain Current ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	ID	±3.3	А		
Pulsed Drain Current ^b		I _{DM}	±25			
Continuous Source Current (Diode Conduction) ^a			2	Α		
	$T_A = 25^{\circ}C$	D_	2.1	w		
Power Dissipation ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	гD	1.3	vv		
Operating Junction and Storage Temperature Range		TJ, Tstg	-55 to 150	°C		

G1

S1

S2

G2

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum Uni		
Maximum Junction-to-Ambient ^a	t <= 10 sec	D	62.5	°C/W	
	t <= 5 sec	$R_{\theta JA}$	110	°C/W	

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

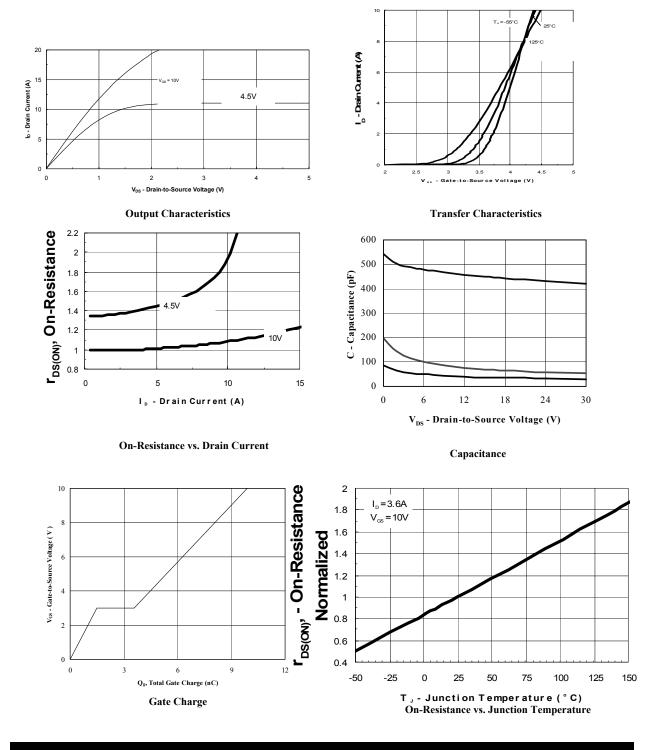
SPECIFICATIONS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)							
			Limits			TL.4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1				
Gate-Body Leakage	IGSS	$V_{DS} = 0 V, V_{GS} = 20 V$			±100	nA	
Zono Coto Valta do Durino Comput	IDSS	$V_{DS} = 60 V$, $V_{GS} = 0 V$			1		
Zero Gate Voltage Drain Current		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			10	uA	
On-State Drain Current ^A	ID(on)	$V_{DS} = 5 V, V_{GS} = 10 V$	20			Α	
A	1DS(on)	$V_{GS} = 10 V$, ID = 4.0 A			89		
Drain-Source On-Resistance ^A		$V_{GS} = 4.5 V$, $I_D = 3.7 A$			104	mΩ	
Forward Tranconductance ^A	gś	$V_{DS} = 15 V$, $I_D = 4.0 A$		11		S	
Diode Forward Voltage	Vsd	$I_S=2.0A$, $V_{GS}=0V$		1.1		V	
Pulsed Source Current (Body Diode) ^A	Ism			5		Α	
Dynamic ^b	-						
Total Gate Charge	Qg	$N_{-} = 20 N_{0} N_{-} = 45 N_{0}$		3.6		nC	
Gate-Source Charge	Qgs	$V_{DS} = 30 V$, $V_{GS} = 4.5 V$, $I_D = 4.0 A$		1.8			
Gate-Drain Charge	Qgd	D = 4.0 A		1.3			
Switching							
Tum-On Delay Time	td(on)			9		nS	
Rise Time	tr	V_{DD} =30 V, R_L =30 Ω , I_D =1 A,		10			
Tum-Off Delay Time	td(off)	$V_{GEN} = 10 V$		21			
Fall-Time	tſ			8			

Notes

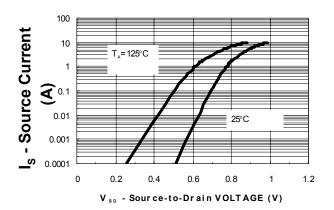
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

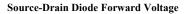
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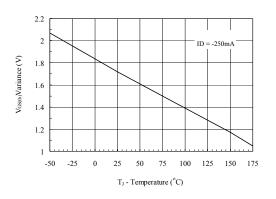
Typical Electrical Characteristics



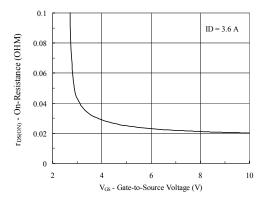
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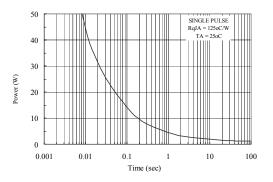








On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power

